

100mA / 50V Digital transistors (with built-in resistors)

DTC124GUA / DTC124GKA

● Applications

Inverter, Interface, Driver

● Features

- 1)The built-in bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 2)Only the on / off conditions need to be set for operation, making the device design easy.
- 3)Higher mounting densities can be achieved.

● Structure

NPN epitaxial planar silicon transistor
(Resistor built-in type)

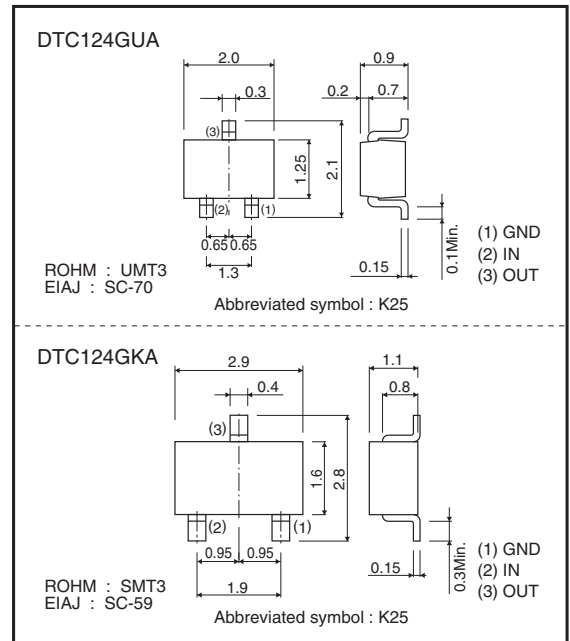
● Packaging specifications

| Part No. | Package | UMT3 | SMT3 |
|-----------|------------------------------|--------|--------|
| | Packaging type | Taping | Taping |
| | Code | T106 | T146 |
| | Basic ordering unit (pieces) | 3000 | 3000 |
| DTC124GUA | | ○ | — |
| DTC124GKA | | — | ○ |

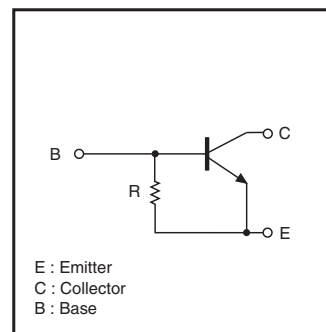
● Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|-----------------------------|------------------|-------------|------|
| Collector-base voltage | V _{CB0} | 50 | V |
| Collector-emitter voltage | V _{CE0} | 50 | V |
| Emitter-base voltage | V _{EB0} | 5 | V |
| Collector current | I _C | 100 | mA |
| Collector power dissipation | P _C | 200 | mW |
| Junction temperature | T _J | 150 | °C |
| Storage temperature | T _{stg} | –55 to +150 | °C |

● Dimensions (Unit : mm)



● Inner circuit



R=22kΩ

● Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|----------------------|------|------|------|------|--|
| Collector-base breakdown voltage | BV _{CBO} | 50 | — | — | V | I _C =50μA |
| Collector-emitter breakdown voltage | BV _{CEO} | 50 | — | — | V | I _C =1mA |
| Emitter-base breakdown voltage | BV _{EBO} | 5 | — | — | V | I _E =330μA |
| Collector cutoff current | I _{CBO} | — | — | 0.5 | μA | V _{CB} =50V |
| Emitter cutoff current | I _{EBO} | 140 | — | 260 | μA | V _{EB} =4V |
| Collector-emitter saturation voltage | V _{CE(sat)} | — | — | 0.3 | V | I _C =10mA, I _B =0.5mA |
| DC current transfer ratio | h _{FE} | 56 | — | — | — | I _C =5mA, V _{CE} =5V |
| Emitter-base resistance | R | 15.4 | 22 | 28.6 | kΩ | — |
| Transition frequency | f _T * | — | 250 | — | MHz | V _{CE} =10V, I _E =-5mA, f=100MHz |

* Characteristics of built-in transistor

● Electrical characteristic curves

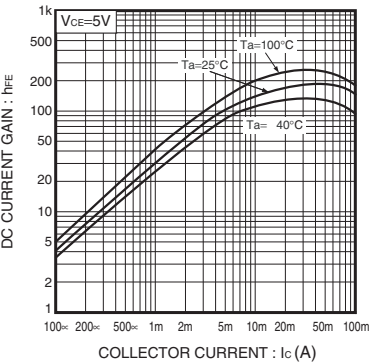


Fig.1 DC current gain vs. Collector current

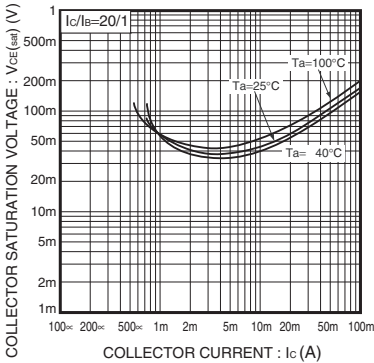


Fig.2 Collector-Emitter saturation voltage vs. Collector current

Notes

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